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MS-001

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use several sheets if necessary)

Boris Kobrin et al. **Applicants** 

January 16, 2004 Filing Date

Unknown Group

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Examiner	Document	Issue				Filing Date
<u>Initial</u>	Number	<u>Date</u>	Name	Class	Subclass	If Appropriate
AND	5,576,247	11/19/96	Yano et al.	437	225	
MK	5,602,671	02/11/97	Hornbeck	359	224	
Inh	5,626,924	05/06/97	Ishikawa	427	759	
M	6,203,505	03/20/01	Jalisi et al.	600	585	
14/2	6,383,642	05/07/02	Le Bellac et al.	428	412	
416	6,576,489	06/10/03	Leung et al.	438	<b>52</b> .	

## U. S. PATENT APPLICATION DOCUMENTS

Examiner Initial	Document Number	Publication Date	Name	Class	Subclass	Filing Date
14	2001/0028924A1	10/11/01	Sherman	427	255.28	05/24/01
1h/	2002/0031618A1	03/14/02	Sherman	427	569	10/09/01
TH	2002/0033229A1	03/21/02	Lebouitz et al.	156	345	04/20/01

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U. S. PATENT	APPLICATION	DOCUMENTS

Examiner	Document	Publication				· · · · · · · · · · · · · · · · · · ·
<u>Initial</u>	Number	Date	<u>Name</u>	<u>Class</u>	<u>Subclass</u>	Filing Date
AN	2002/0076507A1	06/20/02	Chiang et al.	427	569	06/20/02
Anh	2002/0146725A1	10/10/02	Mullen et al.	435	6	11/09/01
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Ath	2003/0138645A1	07/24/03	Gleason et al.	428	447	10/29/02

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Examiner <u>Initial</u>	Document Publication Number Date	Name	Class Subclass	Filing Date  If Appropriate
44	JP 11116278 04/27/99	Hiromi et al.	C03C 17/28	
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